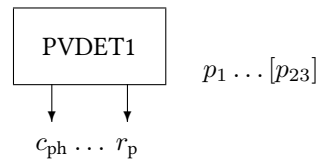


Block PVDET1

The PVDET1 block determines the one-diode-model parameters for c-Si modules from data sheet values and writes a .bp file.



Name	PVDET1
Function	se0025
Inputs	0
Outputs	6
Parameters	18 ... [23]
Strings	6
Group	C

Inputs

None

Outputs

- 1 Coefficient of short-circuit current density c_{ph} / V^{-1}
- 2 Temperature coefficient of short-circuit current $c_t / \text{V}^{-1} \text{K}^{-1}$
- 3 Coefficient of saturation current density (Shockley diode) $c_s / \text{A m}^{-2} \text{K}^{-3}$
- 4 Diode ideality factor α
- 5 Series resistance parameter $r_s / \Omega \text{m}^2$
- 6 Parallel resistance parameter $r_p / \Omega \text{m}^2$

Parameters

- 1 Cells in series per module
- 2 Cells in parallel per module
- 3 Single cell area / m^2
- 4 Module area / m^2
- 5 Maximum power point voltage at STC V_m / V
- 6 Maximum power point current at STC I_m / A
- 7 Open-circuit voltage at STC V_{oc} / V

- 8 Temperature coefficient of open circuit voltage $\alpha_v / \text{V K}^{-1}$
- 9 Short-circuit current at STC I_{sc} / A
- 10 Temperature coefficient of short circuit current $\alpha_i / \text{A K}^{-1}$
- 11 Module tolerance plus / %
- 12 Module tolerance minus / % (≤ 0)
- 13 Characteristic module length / m
- 14 Module mass / kg
- 15 Absorption coefficient
- 16 Emission coefficient
- 17 Specific module heat capacity / $\text{J kg}^{-1} \text{K}^{-1}$
- 18 NOCT temperature / $^{\circ}\text{C}$
- 19 Overwrite mode
 - 0 Generate error (default)
 - 1 Overwrite
- 20 Generate custom module info file record
 - 0 No
 - 1 Yes (In this case it is expected that SP(1) has the form pv9xxxxxx)
- 21 Maximum module voltage / V
- 22 Module width / m
- 23 Module height / m

Strings

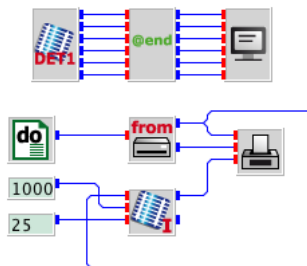
- 1 INSEL module ID (pv000000 defaults to the smallest free number ≥ 900000 in file SP(6).)
- 2 Path to .bp file
- 3 Module name
- 4 Manufacturer
- 5 Cell type (e. g., cristalline)
- 6 Name of custom module info file

Description The parameters of the one- or two-diode model can be calculated uniquely from the data usually provided on the data sheets of PV module manufacturers by a rather simple set of equations. The **PVDET1** block uses these equations to determine the one-diode model parameters.

pvdet1.vseit

Nominal power P_n / W	2.3876
Nominal current I_m / A	4.8487
Nominal voltage V_m / V	0.49243
Short-circuit current I_{sc} / A	5.3125
Open-circuit voltage V_{oc} / V	0.60845
Current temperature coefficient $\alpha_I / \text{mA K}^{-1}$	1.97222
Voltage temperature coefficient $\alpha_V / \text{mV K}^{-1}$	-1.97222
NOCT / $^{\circ}\text{C}$	47 ± 2
Area of a single cell A_c / m^2	0.015625
Number of cells in series N_s	1
Number of cells parallel N_p	1
Module area / m^2	0.015625
Weight / kg	0

The parameters as specified in the table above are used by the **PVDET1** block.



An **ATEND** block is used to ensure that the **SCREEN** block shows the resulting values of the six block parameters only once.

0.27302E+00 0.22463E-03 0.59158E+04 0.10037E+01 0.12164E-03 0.37555E-01

Running this INSEL model results in a file written to the directory specified in [Path to .bp file](#). It is necessary to have write access to this directory. The file name will be as specified in the [INSEL module ID](#) parameter plus extension .bp, so that the example writes the file pvdet1.bp to the current directory.

If several new .bp files are created, it is recommended to use pv900000.bp, pv900001.bp, pv900002.bp etc and to keep track that the numbers are unique.

pvdet1.bp

```
% Filename      pvdet1.bp
% Module        pvdet1
% Manufacturer   Manufacturer
% Cell type     crystalline

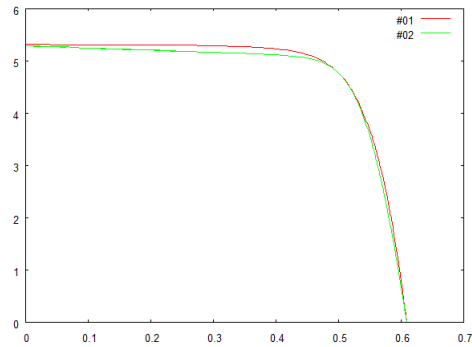
% Mode must be set externally
1      % Number of cells in series N_s per module
1      % Number of cells in parallel N_p per module
1      % Number of modules in series M_s
1      % Number of modules in parallel M_p
0.0156 % Cell area A_c (m^2)
0.016  % Module area A_m (m^2)

% Electrical parameters
1.12   % Band gap (eV)
0.273023E+00 % Short-circuit current parameter C_0 (V^-1)
0.224639E-03 % Isc temperature coefficient C_1 (V^-1 K^-1)
0.591586E+04 % Shockley saturation parameter C_01 (A m^-2 K^-3)
0.000000E+00 % Recombination saturation parameter C_02 (A m^-2 K^-5/2)
0.121641E-03 % Series resistance r_s (Ohm m^2)
0.375550E-01 % Parallel resistance r_p (Ohm m^2)
0.100373E+01 % Shockley diode ideality factor alpha
2.000000 % Recombination diode quality beta
0.000000E+00 % Bishop parameter-1
0.000000E+00 % Bishop parameter-2
0.000000E+00 % Bishop parameter-3
0.0      % Module tolerance plus
0.0      % Module tolerance minus

% Thermal parameters
1.000    % Characteristic module length l_m (m)
1.000    % Module mass m_m (kg)
0.70     % Default absorption coefficient a
0.85     % Default emission factor epsilon
900.0    % Default specific heat of a module C_mod (J kg^-1 K^-1)
47.0     % Nominal operating cell temperature NOCT (degrees C)
25.0     % Intial value of cell temperature (degrees C)

% Numerical parameters (optional)
1E-5     % Error tolerance of voltage of single cell (V)
100      % Maximal number of iterations to solve I/V-equation
```

The .bp file can directly be used in a .insel model. The following graph shows a comparison between the measured curve and the curve based on the obtained parameter set.



Since the open-circuit voltage, short-circuit current and maximum power point data are part of the analytical determination of the one-diode-model parameters, these points are met exactly by the method.

The module can be incorporated into the module data base if the option [Custom module file record](#) is set to [yes](#). In this case a record is added to the file specified in the [Name of custom module info file \(incl. path\)](#) parameter.

At the moment, the only option to include the module in VSEit's PV browsers is to manually copy the new record into the sorted-by-name file `pvModules.dat` which resides in the `resources/data` directory and to copy the new `.bp` file to `resources/data/bp`.

[See also](#) Blocks [PVI](#), [PVV](#), [PVDET2](#).